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SCR's 0.8-10 AMPS SENSITIVE GATE

General Description

The Teccor Electronics, Inc. line of sensitive SCR semiconductors are half-wave unidirectional gate-controlled rectifiers (SCR-thyristor) which complement Teccor's line of power SCRs. This group of packages offers current ratings from 0.8-10 Amps and Voltage ratings from 15-600 Volts with gate sensitivities from 1.0-500 microamps. If gate currents in the 1-50 milliamp ranges are required, please consult Teccor's non-sensitive gate SCR technical data sheets.

Electrically Isolated Packages

This group of Teccor sensitive SCRs is available in a choice of 5 different product packages. The TO-220AB and TO-92 are electrically isolated where the case or tab is internally isolated to allow the use of low cost assembly and convenient packaging techniques. The SOT-89 package is designed for soldering directly to a metalized substrate or the copper side of printed circuit boards.

Glass Passivation

Teccor's line of SCRs features glass passivated junctions to insure long term device reliability and parameter stability. Teccor's glass offers a rugged, reliable barrier against junction contamination.

Tape and reel packaging is available for the TO-92 and SOT-89 packages.

Features

- Electrically Isolated Packages
- High Voltage Capability up to 600 Volts
- High Surge Capability - up to 100 Amps
- Glass Chip Passivation

Electrical Specifications

8872819 TECCOR ELECTRONICS INC

73C 01028

D T-25-01

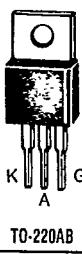
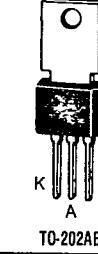
I _{GM}	V _{GRM}	P _{GM}	P _{G(AV)}	I _{TSM}		dv/dt	di/dt	t _{gt}	t _q	I ² t
Peak Gate Current (16)	Peak Reverse Gate Voltage	Peak Gate Power Dissipation (16)	Average Gate Power Dissipation	Peak One Cycle Surge Forward Current (6) (12)		Critical Rate Of Rise Of Off-State Voltage Volts/ μ s	Maximum Rate Of Change Of On-State Current I _{GT} = 50mA With 0.1 μ s Rise Time	Gate Controlled Turn-On Time Gate Pulse = 10mA Min. Width = 5 μ s With Rise Time \leq 0.1 μ s (8)	Circuit Commutated Turn-Off Time (9)	RMS Surge (Non-Repetitive) On-State Current For A Period Of 8.3 msec For Fusing
				Amps						
Amp	Volts	Watts	Watts	60Hz	50Hz	T _C = 25°C	Amps/ μ s	μ s	μ s	Amps ² sec
MAXIMUM	MINIMUM	MAXIMUM	MAXIMUM	MAX	MAX	MINIMUM				MAXIMUM
1.0	5.0	1.0	0.1	20	16	30	50	2.2	50	1.6
1.0	5.0	1.0	0.1	20	16	30	50	2.2	50	1.6
1.0	5.0	1.0	0.1	20	16	30	50	2.2	50	1.6
1.0	5.0	1.0	0.1	20	16	30	50	2.2	50	1.6
1.0	5.0	1.0	0.1	20	16	30	50	2.2	50	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.2	50	1.6
1.0	5.0	1.0	0.1	20	16	15	50	2.2	50	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	15	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	10	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	10	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	40	50	2.5	45	1.6
1.0	5.0	1.0	0.1	20	16	40	50	2.5	45	1.6
1.0	5.0	1.0	0.1	20	16	40	50	2.5	45	1.6
1.0	5.0	1.0	0.1	20	16	40	50	2.5	45	1.6
1.0	5.0	1.0	0.1	20	16	40	50	2.5	45	1.6
1.0	5.0	1.0	0.1	20	16	30	50	2.5	45	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.5	45	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.2	60	1.6
1.0	6.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	6.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	6.0	1.0	0.1	20	16	25	50	2.0	60	1.6
1.0	6.0	1.0	0.1	20	16	25	50	2.0	60	1.6
1.0	6.0	1.0	0.1	20	16	25	50	2.0	60	1.6
1.0	6.0	1.0	0.1	20	16	25	50	2.0	60	1.6
1.0	6.0	1.0	0.1	20	16	25	50	2.0	60	1.6
1.0	6.0	1.0	0.1	20	16	20	50	2.0	60	1.6
1.0	6.0	1.0	0.1	20	16	10	50	2.0	60	1.6
1.0	6.0	1.0	0.1	20	16	30	50	2.2	50	1.6
1.0	6.0	1.0	0.1	20	16	30	50	2.2	50	1.6
1.0	6.0	1.0	0.1	20	16	30	50	2.2	50	1.6
1.0	6.0	1.0	0.1	20	16	30	50	2.2	50	1.6
1.0	6.0	1.0	0.1	20	16	30	50	2.2	50	1.6
1.0	6.0	1.0	0.1	20	16	20	50	2.2	50	1.6
1.0	6.0	1.0	0.1	20	16	15	50	2.2	50	1.6

NOTES TO ELECTRICAL SPECIFICATIONS

- See Figures 1 thru 5 for current ratings at specified operating case temperatures
 - See Figure 6 for I_{GT} vs T_C
 - See Figure 7 for instantaneous on-state current (I_T) vs on-state voltage (V_T) - (typical).
 - See Figure 8 for V_{GT} vs T_C.
 - See Figure 9 for I_H vs T_C.
 - For more than one full cycle see Figure 10
 - T106 & T107 devices also have a pulse peak forward current on-state rating (repetitive) of 75 amperes This rating applies for operation at 60Hz, 75°C maximum lead (or anode) lead temperature, switching from 80 volts peak, sinusoidal current pulse width of 10 μ sec minimum, 15 μ sec maximum
 - See Figure 11 for I_t vs T_C
 - Test Conditions as Follows:
- T_C = 80°C rectangular current waveform rate of rise of current \leq 10 amps/ μ sec Rate of reversal of

- current \leq 5 amps/ μ sec I_TM = 1 amp (50 μ sec Pulse) Repetition Rate = 60pps V_{RMM} = Rated VR = 15 volts minimum, V_{DRM} = Rated rate of rise reapplyd forward blocking voltage = 5 volts/ μ sec Gate Bias = 0 volts, 100 OHMS (during turn-off time interval)
- Test condition is maximum rated RMS current except TO-92 devices are 1/2 APK, T106/T107 devices are 4 APK
 - VD = 6 VDC, RL = 100Ω. See Figure 14 for simple test circuit for measuring gate trigger voltage and gate trigger current
 - See Figure 1 thru 5 for maximum allowable case temperature @ maximum rated current
 - I_{GT} = 500 μ A maximum for T_C = -40°C for T106 devices
 - I_H = 10mA maximum for T_C = -65°C for 2N5060 Series and 2N6564 Series devices
 - I_H = 6mA maximum for T_C = -40°C for T106 devices
 - Pulse Width \leq 3 μ s
 - I_{GT} = 350 μ A maximum @ T_C = -65°C for 2N5060 Series and 2N6564 Series devices

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TYPE	Part Number		IT	V _{DRM} & V _{RRM}	IGT	IDRM & I _{RRM}	VTM	VGT		IH			
	Isolated	Non-Isolated						Peak Off-State Current @ V _{DRM} & V _{RRM}	Peak On-State Voltage T _C = 25°C (3) (10)				
	 K A G		 K A G		Volts	μAmps	Volts	DC Gate Trigger Voltage (4) (11)		DC Holding Current Initial On-State Current = 20mA (5) (15)			
	TO-220AB	TO-202AB	IT(RMS)	IT(AV)				T _C = 25°C	T _C = 100°C				
FOR DIMENSIONAL OUTLINE & PACKAGE VARIATIONS SEE PG. 67													
1.6 Amps	S0301LS1		1.6	1.0	30	50	2.0	100	1.6	1.0	0.8	0.2	6.0
	S0301LS2		1.6	1.0	30	200	2.0	100	1.6	1.0	0.8	0.2	6.0
	S0301LS3		1.6	1.0	30	500	2.0	100	1.6	1.0	0.8	0.2	8.0
	S0501LS1		1.6	1.0	50	50	2.0	100	1.6	1.0	0.8	0.2	6.0
	S0501LS2		1.6	1.0	50	200	2.0	100	1.6	1.0	0.8	0.2	6.0
	S0501LS3		1.6	1.0	50	500	2.0	100	1.6	1.0	0.8	0.2	6.0
	S1001LS1		1.6	1.0	100	50	2.0	100	1.6	1.0	0.8	0.2	8.0
	S1001LS2		1.6	1.0	100	200	2.0	100	1.6	1.0	0.8	0.2	6.0
	S1001LS3		1.6	1.0	100	500	2.0	100	1.6	1.0	0.8	0.2	6.0
	S2001LS1		1.6	1.0	200	50	2.0	100	1.6	1.0	0.8	0.2	8.0
	S2001LS2		1.6	1.0	200	200	2.0	100	1.6	1.0	0.8	0.2	6.0
	S2001LS3		1.6	1.0	200	500	2.0	100	1.6	1.0	0.8	0.2	6.0
	S4001LS1		1.6	1.0	400	50	2.0	100	1.6	1.0	0.8	0.2	6.0
	S4001LS2		1.6	1.0	400	200	2.0	100	1.6	1.0	0.8	0.2	6.0
	S4001LS3		1.6	1.0	400	500	2.0	100	1.6	1.0	0.8	0.2	8.0
	S0303LS1		3.0	1.9	30	50	2.0	100	1.6	1.0	0.8	0.2	6.0
	S0303LS2		3.0	1.9	30	200	2.0	100	1.6	1.0	0.8	0.2	6.0
	S0303LS3		3.0	1.9	30	500	2.0	100	1.6	1.0	0.8	0.2	8.0
	S0503LS1		3.0	1.9	50	50	2.0	100	1.6	1.0	0.8	0.2	6.0
	S0503LS2		3.0	1.9	50	200	2.0	100	1.6	1.0	0.8	0.2	6.0
	S0503LS3		3.0	1.9	50	500	2.0	100	1.6	1.0	0.8	0.2	6.0
	S1003LS1		3.0	1.9	100	500	2.0	100	1.6	1.0	0.8	0.2	8.0
	S1003LS2		3.0	1.9	100	200	2.0	100	1.6	1.0	0.8	0.2	6.0
	S1003LS3		3.0	1.9	100	500	2.0	100	1.6	1.0	0.8	0.2	6.0
	S2003LS1		3.0	1.9	200	50	2.0	100	1.6	1.0	0.8	0.2	8.0
	S2003LS2		3.0	1.9	200	200	2.0	100	1.6	1.0	0.8	0.2	6.0
	S2003LS3		3.0	1.9	200	500	2.0	100	1.6	1.0	0.8	0.2	6.0
	S4003LS1		3.0	1.9	400	50	2.0	100	1.6	1.0	0.8	0.2	6.0
	S4003LS2		3.0	1.9	400	200	2.0	100	1.6	1.0	0.8	0.2	6.0
	S4003LS3		3.0	1.9	400	500	2.0	100	1.6	1.0	0.8	0.2	8.0
4.0 Amps	T106Q1		4.0	2.5	15	200	2.0	100	2.2	1.0	0.8		5.0
	T106Y1		4.0	2.5	30	200	2.0	100	2.2	1.0	0.8		5.0
	T106F1		4.0	2.5	50	200	2.0	100	2.2	1.0	0.8		5.0
	T106A1		4.0	2.5	100	200	2.0	100	2.2	1.0	0.8		5.0
	T106B1		4.0	2.5	200	200	2.0	100	2.2	1.0	0.8		5.0
	T106C1		4.0	2.5	300	200	2.0	100	2.2	1.0	0.8		5.0
	T106D1		4.0	2.5	400	200	2.0	100	2.2	1.0	0.8		5.0
	T106E1		4.0	2.5	500	200	2.0	100	2.2	1.0	0.8		5.0
	T106M1		4.0	2.5	600	200	2.0	100	2.2	1.0	0.8		5.0
	T107Q1		4.0	2.5	15	500	2.0	100	2.5	1.0	0.8		5.0
	T107Y1		4.0	2.5	30	500	2.0	100	2.5	1.0	0.8		6.0
	T107F1		4.0	2.5	50	500	2.0	100	2.5	1.0	0.8		6.0
	T107A1		4.0	2.5	100	500	2.0	100	2.5	1.0	0.8		6.0
	T107B1		4.0	2.5	200	500	2.0	100	2.5	1.0	0.8		6.0
	T107C1		4.0	2.5	300	500	2.0	100	2.5	1.0	0.8		6.0
	T107D1		4.0	2.5	400	500	2.0	100	2.5	1.0	0.8		6.0
	T107E1		4.0	2.5	500	500	2.0	100	2.5	1.0	0.8		6.0
	T107M1		4.0	2.5	600	500	2.0	100	2.5	1.0	0.8		6.0

GENERAL NOTES

- The case temperature (T_C) is measured as shown on dimensional outline drawings. See package dimensions section of this catalog.
- All measurements (except IGT) are made with an external resistor RGK = 1kΩ unless otherwise noted
- All measurements are made at 60Hz with a resistive load at an ambient temperature of +25°C unless otherwise specified

- Operating temperature (T_J) is -65°C to +110°C for "EC" Series devices and SOT-89 devices. -65°C to +125°C for "2N" Series devices; and -40°C to +110°C for all others
- Storage temperature range (T_S) is -65°C to +150°C for TO-92 and SOT-89 devices; -40°C to +150°C for TO-202 devices, and -40°C to +125°C for all others
- Lead solder temperature is a maximum of +230°C for 10 seconds maximum ≥ 1/16" from case (For SOT-89 devices see soldering notes on page 101.)

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THERMAL RESISTANCE (STEADY STATE) R_{eJC}/R_{eJA} °C/W (TYPICAL)						
Type	PLASTIC TO-92	SURFACE MOUNT SOT-89	THERMOTAB TO-220AB	TYPE 2 TO-202AB	TYPE 1 & 3 TO-202AB	
0.8 Amp	75/160					
1.2 Amps		50				
1.6 Amps			6.5			
3.0 Amps			6.0			
4.0 Amps	T106— T107 "N" PACKAGE			10/100	6.2/80	
6.0 Amps				9.5/70	5.6/52	
8.0 Amps			4.0		4.3	
10.0 Amps			3.4		3.9	

ELECTRICAL ISOLATION FROM LEADS TO CASE
(U.L. RECOGNIZED FILE #E71639)

TYPE	PLASTIC TO-92	THERMOTAB TO-220AB
VAC (RMS)	STANDARD	—
1600	NO	STANDARD
2500	NO	OPTIONAL*

*For 4000V Isolation use "V" Suffix

FIGURE 1 — Maximum Allowable Case Temperature vs RMS On-State Current

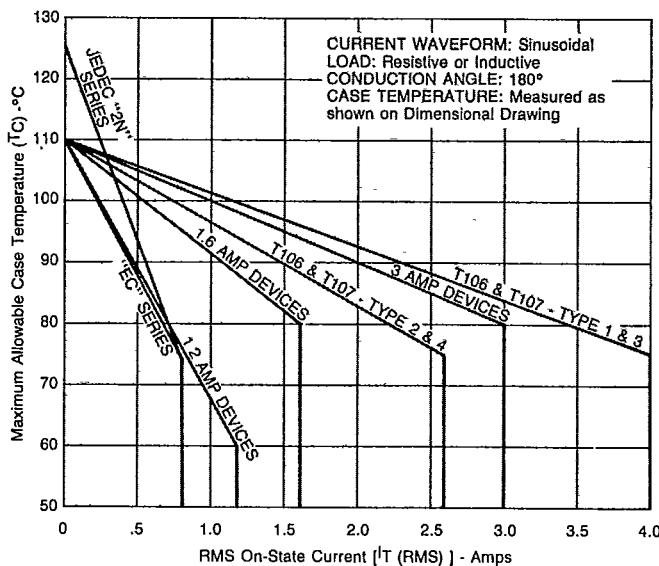
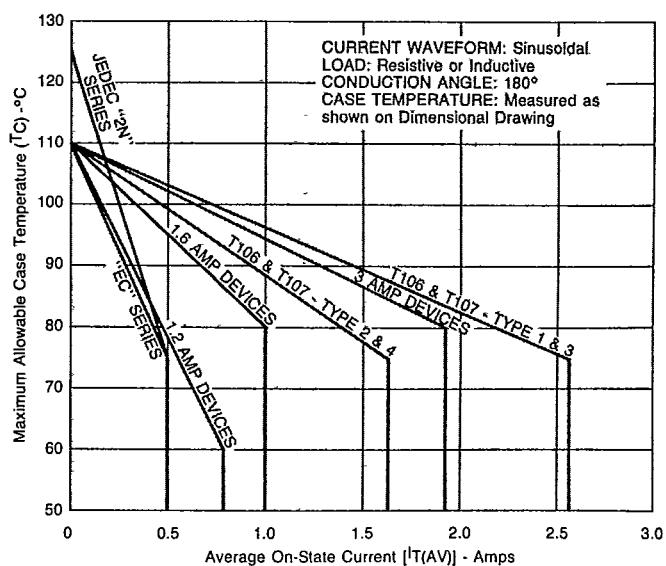


FIGURE 2 — Maximum Allowable Case Temperature vs Average On-State Current



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FIGURE 3A — Maximum Allowable Ambient Temperature vs On-State Current

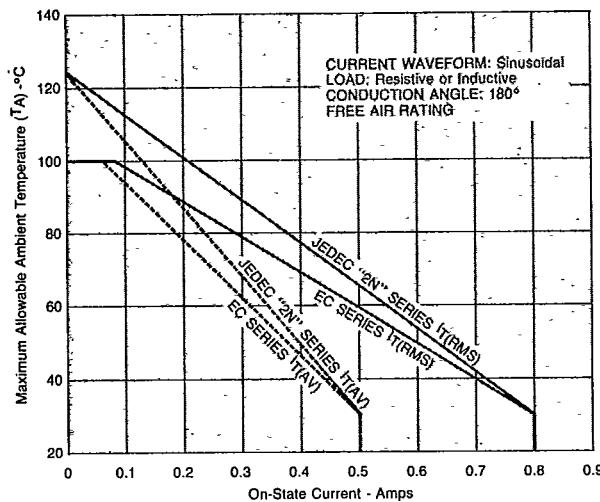


FIGURE 3B — Maximum Allowable Ambient Temperature vs On-State Current

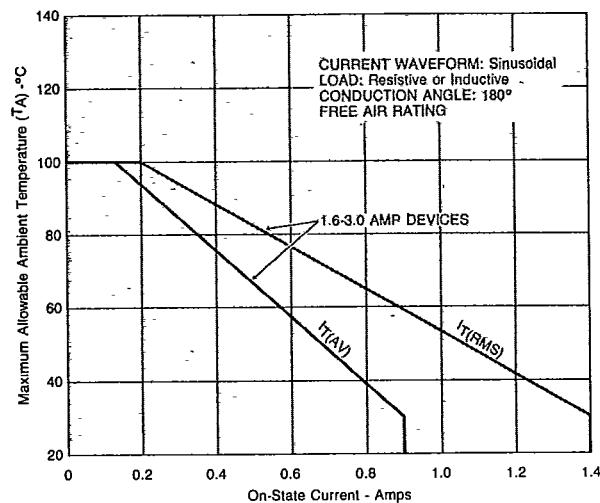


FIGURE 3C — Maximum Allowable Ambient Temperature vs RMS On-State Current

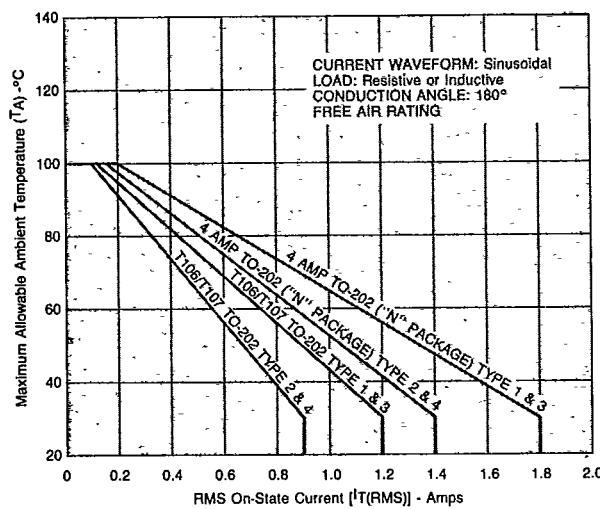
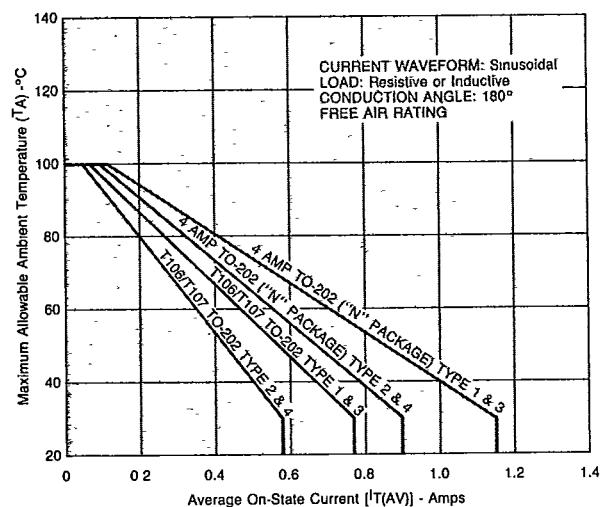


FIGURE 3D — Maximum Allowable Ambient Temperature vs Average On-State Current



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FIGURE 4 — Maximum Allowable Case Temperature vs RMS On-State Current

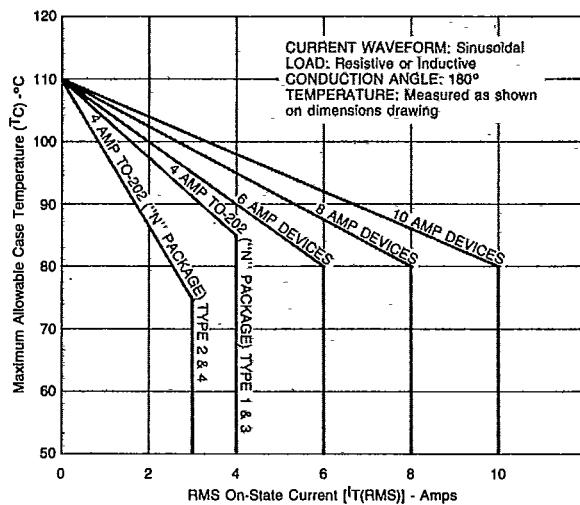


FIGURE 5 — Maximum Allowable Case Temperature vs Average On-State Current

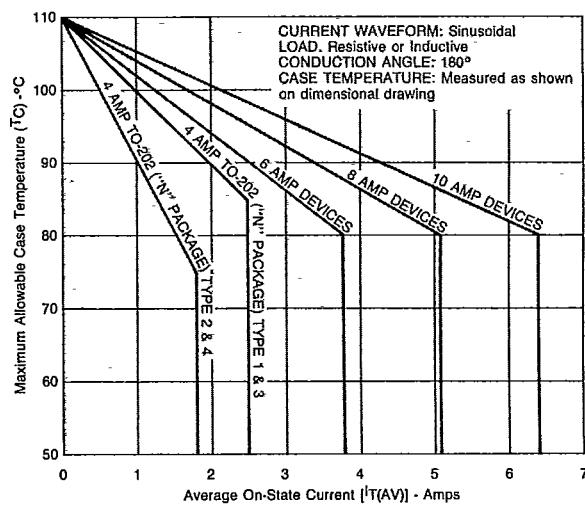


FIGURE 6 — Normalized DC Gate-Trigger Current vs Case Temperature

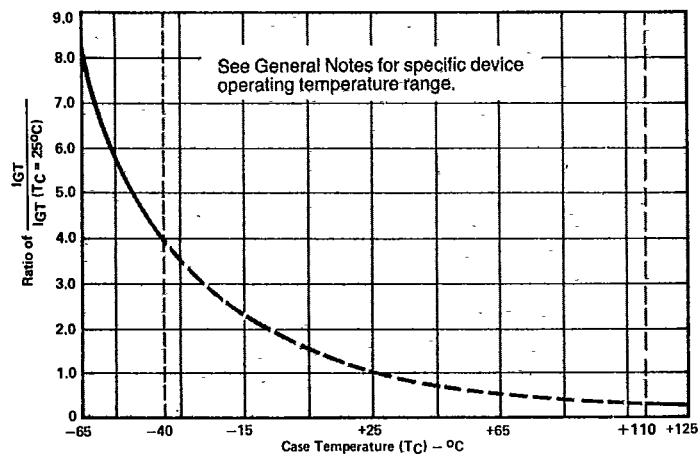
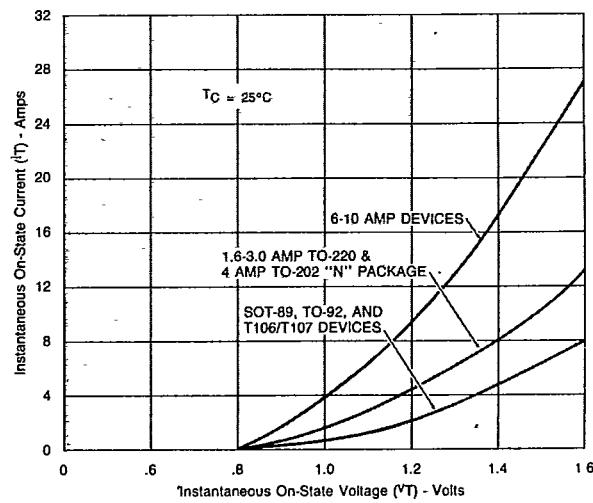


FIGURE 7 — Instantaneous On-State Current vs On-State Voltage (Typical)



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FIGURE 8 — Normalized DC Gate-Trigger Voltage vs Case Temperature

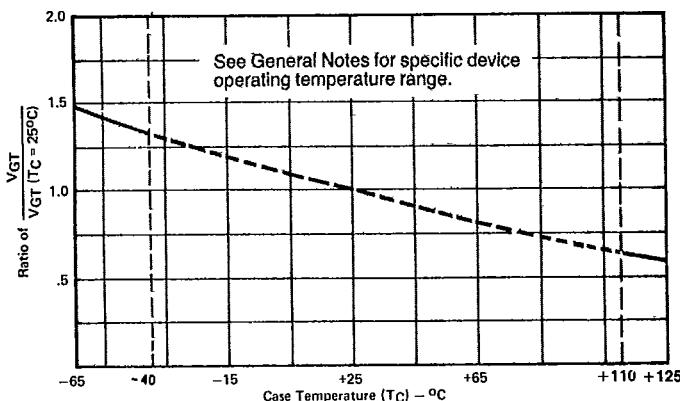


FIGURE 9 — Normalized DC Holding Current vs Case Temperature

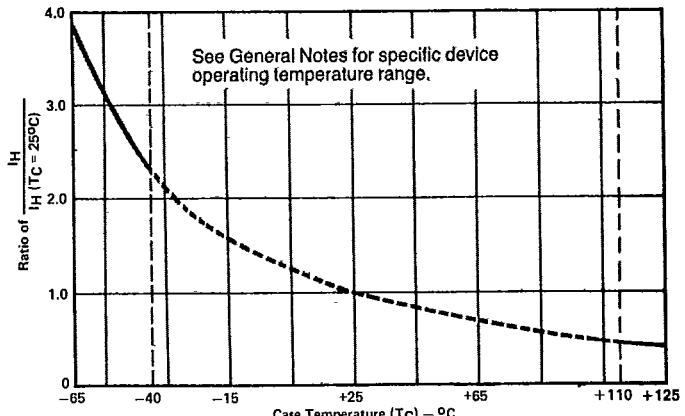
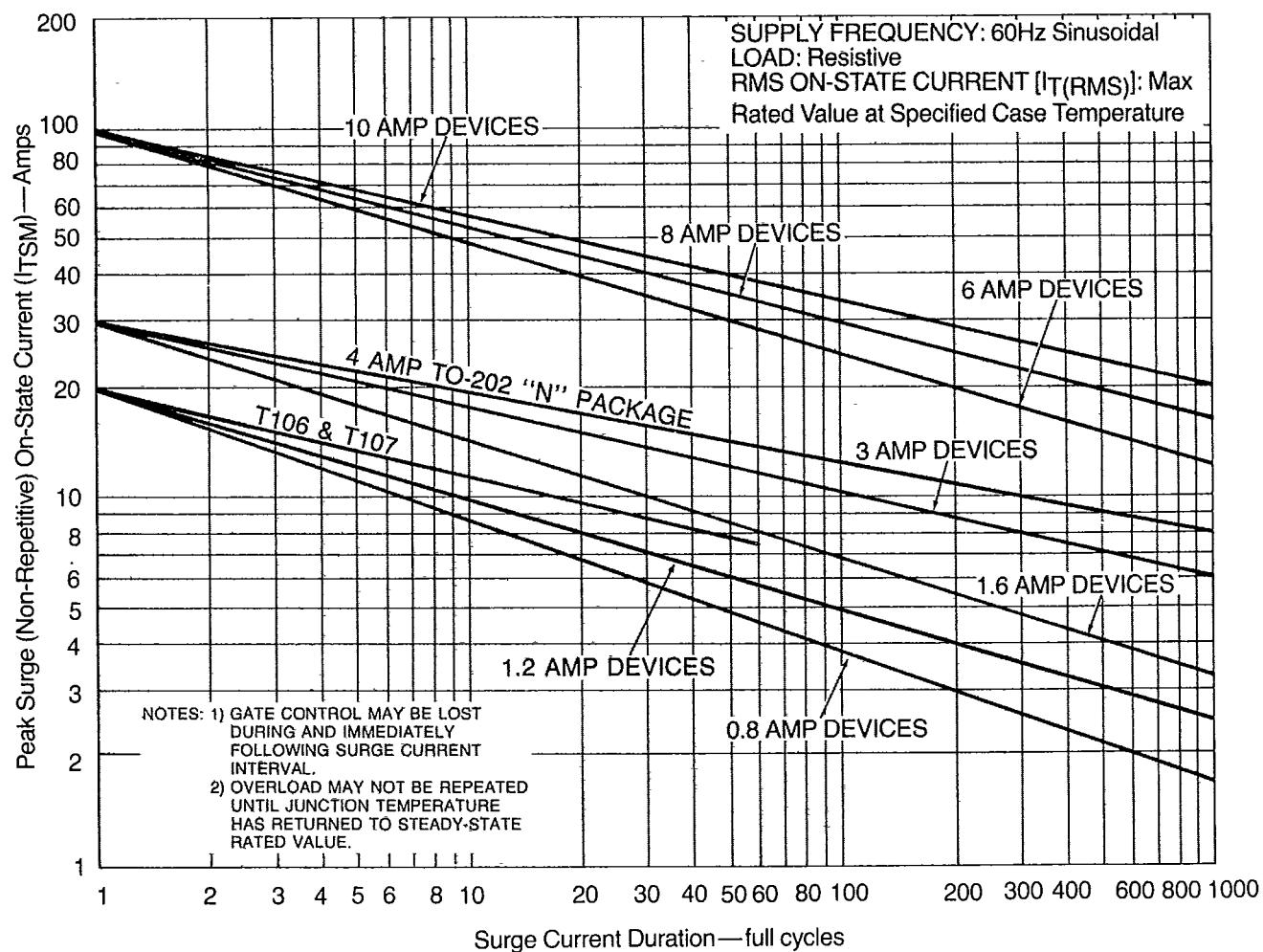


FIGURE 10 — Peak Surge On-State Current vs Surge Current Duration



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FIGURE 11 — Typical Turn-On Time
vs Gate Trigger Current

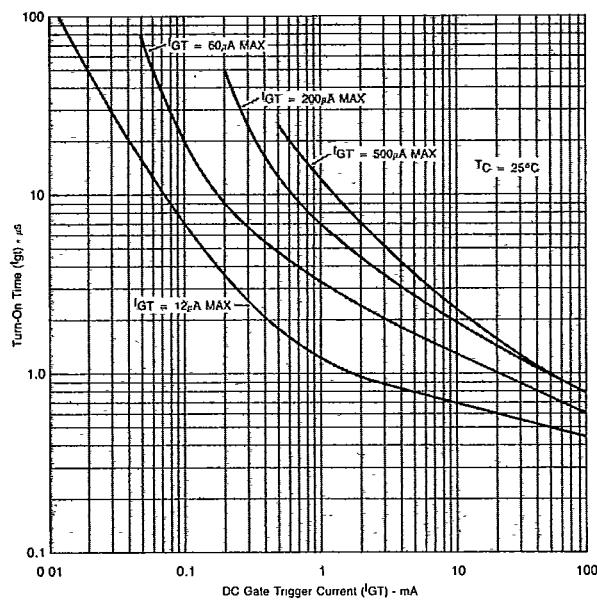


FIGURE 12 — Power Dissipation (Typical)
vs RMS On-State Current

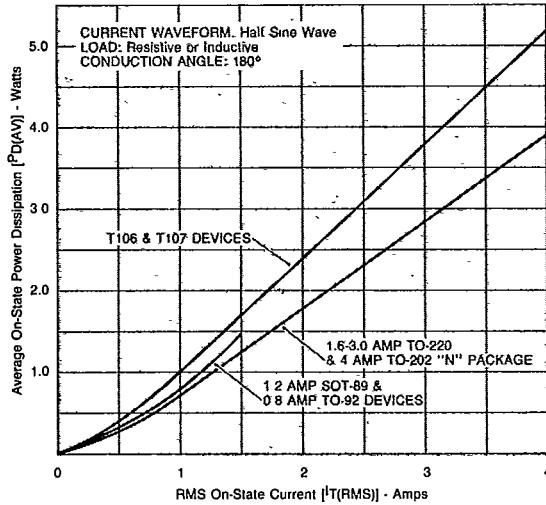


FIGURE 13 — Power Dissipation (Typical)
vs RMS On-State Current

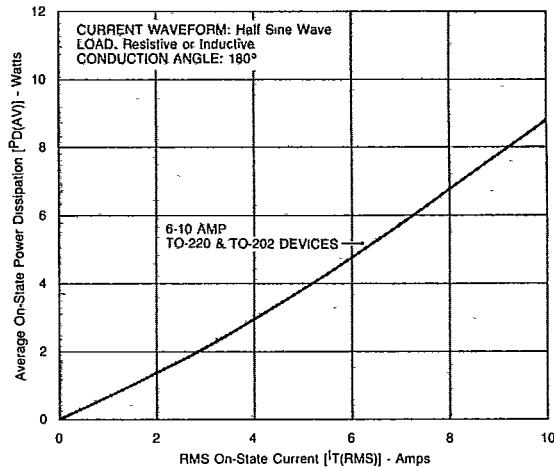
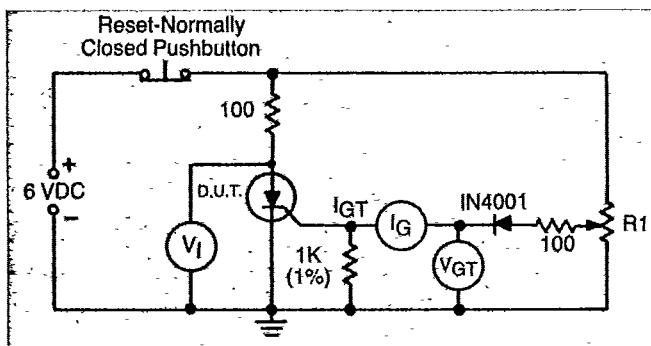


FIGURE 14 — Simple Test Circuit For Gate Trigger
Voltage and Current Measurement



NOTE:

V_1 —0-10 Volt DC meter
 V_{GT} —0-1 Volt DC meter
 I_G —0-1 mA DC milliammeter
 R_1 —1K potentiometer

To measure gate trigger voltage and current, raise gate voltage (V_{GT}) until meter reading V_1 drops from 6 Volts to 1 Volt. Gate trigger voltage is the reading on V_{GT} just prior to V_1 dropping. Gate trigger current I_{GT} can be computed from the relationship:

$$I_{GT} = I_G - \frac{V_{GT}}{1000} \text{ Amps}$$

where I_G is reading (in Amps) on meter just prior to V_1 dropping. NOTE: I_{GT} may turn out to be a negative quantity (trigger current flows out from gate lead).